

Vishay Siliconix

N-Channel 100 V (D-S) MOSFET

DESCRIPTION

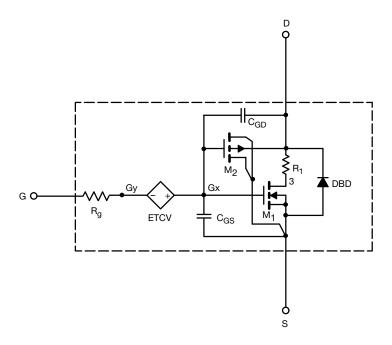
The attached SPICE model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over -55 °C to +125 °C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched $C_{\rm gd}$ model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

CHARACTERISTICS

- N-channel vertical DMOS
- · Macro model (subcircuit model)
- Level 3 MOS
- Apply for both linear and switching application
- Accurate over -55 °C to +125 °C temperature range
- · Model the gate charge

SUBCIRCUIT MODEL SCHEMATIC



Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits





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SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate-source threshold voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$	2.9	-	V
Drain-source on-state resistance ^a	В	$V_{GS} = 10 \text{ V}, I_D = 15 \text{ A}$	0.0053	0.0053	Ω
	R _{DS(on)}	V _{GS} = 7.5 V, I _D = 15 A	0.0058	0.0057	
Forward transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 15 A	54	60	S
Diode forward voltage	V _{SD}	I _S = 5 A	0.73	0.75	V
Dynamic ^b					
Input capacitance	C _{iss}	V _{DS} = 50 V, V _{GS} = 0 V, f = 1 MHz	4430	4230	pF
Output capacitance	C _{oss}		361	346	
Reverse transfer capacitance	C _{rss}		42	18	
Total gate charge	0	V _{DS} = 50 V, V _{GS} = 10 V, I _D = 15 A	55	56	nC
	Qg		42	43	
Gate-source charge	Q _{gs}	$V_{DS} = 50 \text{ V}, V_{GS} = 7.5 \text{ V}, I_D = 15 \text{ A}$	17.5	17.5	
Gate-drain charge	Q _{gd}]	7	7	

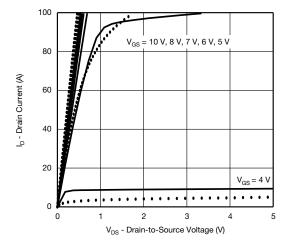
Notes

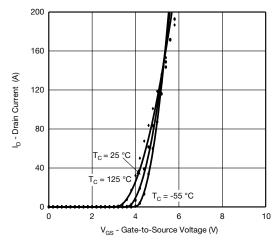
- a. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%$
- b. Guaranteed by design, not subject to production testing

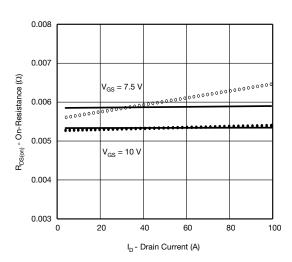
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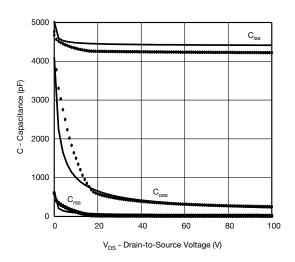
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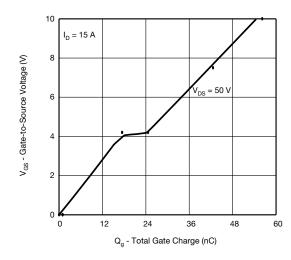
COMPARISON OF MODEL WITH MEASURED DATA ($T_J = 25 \, ^{\circ}\text{C}$, unless otherwise noted)

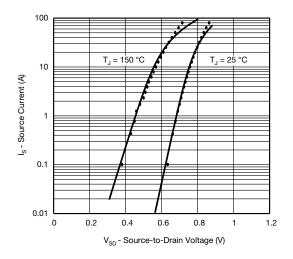












Note

 Dots and squares represent measured data Copyright: Vishay Intertechnology, Inc.



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